NSN 5961-00-311-5340

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-311-5340 **Inclosure Material:** Glass **Overall Length:** 0.900 inches **Overall Diameter:** 0.295 inches **Mounting Method:** Compression **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 35.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset **Power Rating Per Characteristic:** 3.5 watts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Diode mtd in a rexolite sleeve; two end plugs and cap; junction pattern arrangement: pn **Precious Material And Location:** End plugs and cap plated gold **Precious Material:** Gold **Terminal Type And Quantity:** 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No